# Electronic Version v1.1

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SUBMISSION TYPE:	CORRECTIVE ASSIGNMENT
NATURE OF CONVEYANCE:	Corrective Assignment to correct the Name of Assignee previously recorded on Reel 015609 Frame 0839. Assignor(s) hereby confirms the THE JAPAN AND SCIENCE TECHNOLOGY AGENCY should readJAPAN SCIENCE AND TECHNOLOGY AGENCY

## CONVEYING PARTY DATA

Name	Execution Date
THE REGENTS OF THE UNIVERSITY OF CALIFORNIA	01/19/2005

### RECEIVING PARTY DATA

Name:	JAPAN SCIENCE AND TECHNOLOGY AGENCY
Street Address:	4-1-8, Honcho, Kawaguchi City
City:	Saitama Prefecture
State/Country:	JAPAN
Postal Code:	332-0012

### PROPERTY NUMBERS Total: 2

Property Type	Number
Application Number:	60433843
PCT Number:	US0321918

### CORRESPONDENCE DATA

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### NAME OF SUBMITTER:

George H. Gates

Total Attachments: 1 source=Page0001#page1.tif \$80.00

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#### **ASSIGNMENT**

U.C. Case No. 2003-224

G & C Case No. 30794.93

For good and valuable consideration, the receipt of which is hereby acknowledged, ASSIGNOR, THE REGENTS OF THE UNIVERSITY OF CALIFORNIA, hereby sells, assigns and transfers to ASSIGNEE, THE JAPAN SCIENCE AND TECHNOLOGY AGENCY, a statutory corporation of the Japanese government, having its principal offices located at 4-1-8, Honcho, Kawaguchi City, Saitama Prefecture, 332-0012, Japan, and the successors, assigns and legal representatives of the ASSIGNEE, an undivided one-half (1/2) or fifty percent (50%) interest in and to the following patent applications:

- U.S. provisional application serial no. <u>60/433,843</u>, filed on <u>December 16, 2002</u>, by <u>Benjamin A.</u> <u>Haskell, Michael D. Craven, Paul T. Fini, Steven P. DenBaars, James S. Speck and Shuji</u> <u>Nakamura</u>, and entitled <u>GROWTH OF REDUCED DISLOCATION DENSITY NON-</u> <u>POLAR GALLIUM NITRIDE BY HYDRIDE VAPOR PHASE EPITAXY</u>;
- P.C.T application serial no. <u>US03/21918</u>, filed on <u>July 15, 2003</u>, by <u>Benjamin A. Haskell, Michael</u> <u>D. Craven, Paul T. Fini, Steven P. DenBaars, James S. Speck, and Shuji Nakamura, and entitled <u>GROWTH OF REDUCED DISLOCATION DENSITY NON-POLAR GALLIUM</u> <u>NITRIDE BY HYDRIDE VAPOR PHASE EPITAXY</u>; and</u>

and any legal equivalent thereof in any country, including the right to claim priority and, in and to, all Letters Patent to be obtained therefor, and any continuation, division, continuation-in-part, extension, conversion to 35 U.S.C. §111(a) or substitute thereof, and any reissue, reexamination or extension of said Letters Patent and all rights under all International Conventions for the Protection of Industrial Property;

Executed this 19 day of January, ..., 2005.

Signed: <u>Linda S. Stevenson</u> Name: Linda S. Stevenson

Title: Manager, Patent Prosecution University of California Office of Technology Transfer

assign.doc

### **RECORDED: 02/02/2005**